Docket No.

202450US0

ÉS PATENT AND TRADEMARK OFFICE

RECEIVED 0CT 1 6 2003 TC 1700

IN RE APPLICATION OF:

Atsushi SHIOTA, et al

SERIAL NO: 09 770,289

GAU:

1712

FILED: FOR:

January 29, 2001

EXAMINER: FEELY, M.J.

SEMICONDUCTOR DEVICE

PROCESS FOR PRODUCING SILICA-BASED FILM, SILICA-BASED FILM, INSULATING FILM, AND

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant(s) wish to disclose the following information.

REFERENCES

- The applicant(s) wish to make of record the references listed on the attached form PTO-1449. Copies of the listed references are attached, where required, as are either statements of relevancy or any readily available English translations of pertinent portions of any non-English language references.
- ☐ A check is attached in the amount required under 37 CFR §1.17(p).

RELATED CASES

- ☐ Attached is a list of applicant's pending application(s) or issued patent(s) which may be related to the present application. A copy of the patent(s), together with a copy of the claims and drawings of the pending application(s) is attached along with PTO 1449.
- ☐ A check is attached in the amount required under 37 CFR §1.17(p).

CERTIFICATION

- ☐ Each item of information contained in this information disclosure statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of
- ☐ No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR \$1.56(c) more than three months prior to the filing of this statement.

DEPOSIT ACCOUNT

■ Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment form is enclosed herewith, or credit any overpayment to deposit account number 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted.

OBLON, SPIVAK, McCLELLAND,

MAIER & NEUSTADT, P.C

Norman F. Oblon

Registration No. 24,618

COMMIN SO

produktiation No. 1886

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Form PTO 1449 U.S. DEPARTMENT OF COMI (Modified) PATENT AND TRADEMARK (MARK OFFICE	202450US0		09/770,289		
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LIST OF	REFER	ENCES CITED BY APP	LICANT	Atsushi SHIOTA, et al.				
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EXAMINER INITIAL		DOCUMENT	DATE	NAME	CLASS	SUB CLASS		
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		DOCUMENT NUMBER	DATE		COUNTRY JAPAN (English-language Abstract only)		YES NO	
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	AY	Applied Materials' as	ssertion that M	atthew Ross is a co-inventor of the 09/7	Type 602,01	modilon. Of		
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